Ka-Band High Power Terminated SPDT PIN Switch 26 - 40 GHz



MASW-011036 Rev. V8

Features

- Broadband Performance, 26 to 40 GHz •
- Low Loss <1 dB
- High Isolation >38 dB .
- Up to 13 W CW Power, +85°C
- Die with G-S-G RF Pads and DC Bias Pads
- Includes DC Blocks and RF Bias Networks
- 23 dBm power handling in terminated port
- **RoHS*** Compliant •

Applications

Aerospace & Defense

Description

The MASW-011036 is a high power SPDT with 50 Ω terminated RF ports. This broadband, high linearity, SPDT switch die was developed for Ka-Band applications that require up to 13 Watts CW power handling at an environmental temperature of +85°C while maintaining low insertion loss and high isolation.

The SPDT MMIC utilizes MACOM's proven AlGaAs PIN diode technology. The switch is fully passivated with silicon nitride and has an added polymer layer for scratch protection. The protective coating prevents damage to the junction and the anode air-bridge during handling and assembly. The die has backside metallization to facilitate an epoxy die attach process.

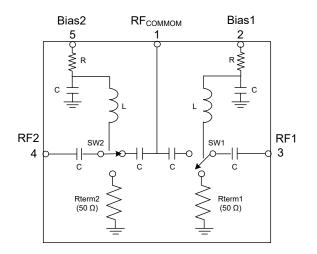
Part Number Package Separated Die on 7" Grip MASW-011036-1413WR Ring¹, Electronic Map Separated Die on 7" Grip MASW-011036-1413RI Ring¹, Inked Wafer MASW-011036-14130G Die in Gel Pack¹ MASW-011036-001SMB Sample Evaluation Board

1. Die quantity varies.

1

Ordering Information¹

Functional Diagram



Pin Configuration:

(Back Metal is RF, DC, and Thermal Ground)

Pin #	Function
1	RF _{COMMON}
2	BIAS 1
3	RF1
4	RF2
5	BIAS 2

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

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MASW-011036 Rev. V8

Electrical Specifications: Freq. = 28 - 30 GHz, T_A = +25°C, +4 V @ +25 mA / -15 V @ 0 mA, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	26 - 28 GHz 28 - 32 GHz 32 - 36 GHz 36 - 40 GHz	dB	_	0.80 0.70 0.70 1.5	 1.0
Isolation ²	26 - 28 GHz 28 - 32 GHz 32 - 36 GHz 36 - 40 GHz	dB	34 	38 40 40 40	
Input / Output Return Loss On state	26 - 28 GHz 28 - 32 GHz 32 - 36 GHz 36 - 40 GHz	dB	13 —	20 20 20 12	
RF1, 2 Return Loss, Off state	26 - 28 GHz 28 - 32 GHz 32 - 36 GHz 36 - 40 GHz	dB	7.5 —	8 10 18 18	
Switching Speed-T _{ON}	50% DC to 90% RF	ns	_	30	
Switching Speed-T _{OFF}	50% DC to 10% RF	ns	_	21	
Rise Time -T _{RISE}	10% to 90% RF	ns	_	10	
Fall Time - T _{FALL}	90% to 10% RF	ns		8	_
CW Input Power ³	-25 V @ +85°C	dBm	_	41.2	
Reverse Bias Voltage ³	_	V	-32	-15	-5
Reverse Bias Current ³	-15 V	nA		25	_
Forward Bias Current ⁴	+4 V	mA		25	—

2. Isolation defined with 1 port in low loss state.

3. Reverse bias voltage should be determined based on working conditions. For example, -25 V @ 41.2 dBm input power. For lower power applications, a less negative voltage can be used. R. Caverly and G. Hiller, "Establishing the Minimum Reverse Bias for a P-I-N Diode in a High Power Switch," IEEE Transactions on Microwave Theory and Techniques, Vol.38, No.12, December 1990.

4. Forward bias voltage should be determined based on working conditions.

²

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MASW-011036

Rev. V8

Absolute Maximum Ratings^{5,6}

Parameter	Absolute Maximum
DC Reverse Bias Voltage	50 V
Forward Bias Current	60 mA
CW Incident Power (Low Loss Port)	41 dBm @ +85°C 43 dBm @ +25°C
CW Incident Power (Terminated Port)	23 dBm @ +85°C 26 dBm @ +25°C
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

5. Exceeding any one or combination of these limits may cause permanent damage to this device.

6. MACOM does not recommend sustained operation near these survivability limits.

Truth Table

RF _{COMMOM} Path	Bias 1	Bias 2
RF1 Insertion Loss RF2 Isolation	-15 V (0 mA)	+4 V (+25 mA)
RF2 Insertion Loss RF1 Isolation	+4 V (+25 mA)	-15 V (0 mA)

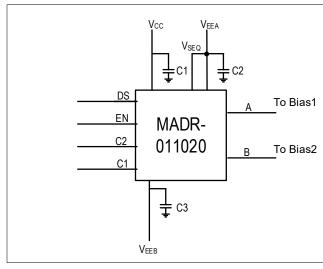
Handling Procedures

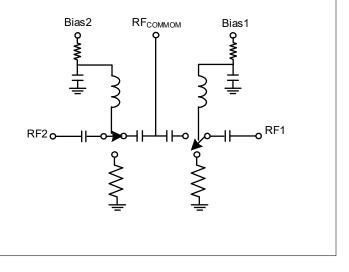
Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM class 1A devices.

MASW-011036 with MADR-011020 Driver Application Schematic⁷





7. V_{CC} = +5 V and V_{EEB} = -24 V.

Parts List

Part	Value
C1, C3	0.1 µF
C2	47 pF

Switch Minimum Reverse Bias Voltage^{3,8}

Frequency (GHz)	DC Voltage (V) Bias1 & Bias2
26	-16
30	-14
34	-12
38	-11
40	-11

8. Calculated (see note 3) minimum DC bias voltage to maintain low loss under 41.2 dBm of power with 1.5:1 VSWR.

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3

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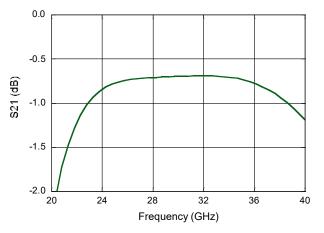
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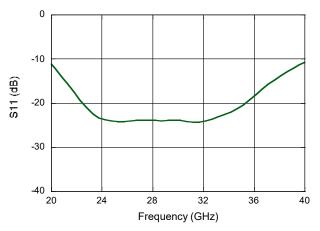
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Typical Performance @ +25°C

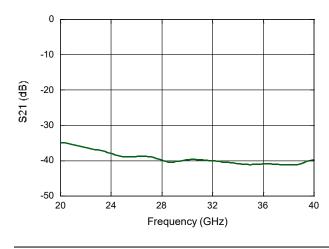
Insertion Loss (On State)



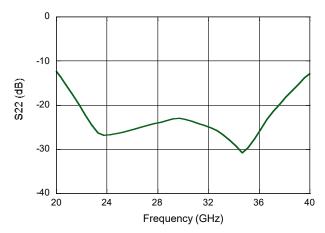
RF_{COMMON} Return Loss (On State)



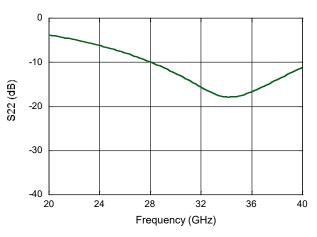
Isolation (Off State)



RF1, 2 Return Loss (On State)



RF1, 2 Return Loss (Off State)



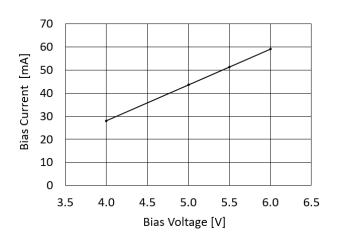
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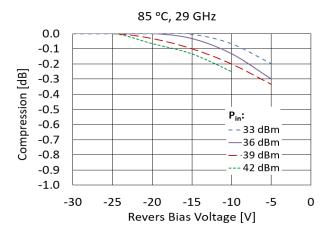


MASW-011036 Rev. V8

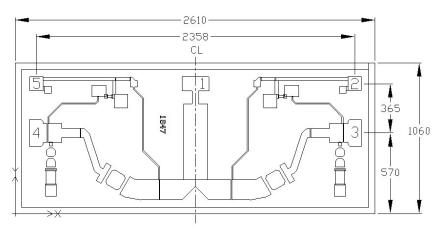


Forward Bias Current vs Bias Voltage

Compression vs Reverse Bias Voltage



Die Outline



Dimensions indicated in μ m. Die Thickness: 100 μ m RF Pads (1, 3, 4): 100 x 200 μ m. DC Bias Pads (2 & 5): 100 x 100 μ m. Meets JEDEC moisture sensitivity level 1 requirements.

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MASW-011036 Rev. V8

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